

MOS INTEGRATED CIRCUIT μ PD75402A(A)

4 BIT SINGLE-CHIP MICROCOMPUTER

The μ PD75402A(A) is a CMOS single-chip microcomputer which uses the 75X series architecture. It operates at high speed with a minimum instruction execution time of 0.95 μ s.

The μ PD75P402 is also available for system development evaluation. It contains one-time PROM instead of mask ROM used in the μ PD75402A(A).

The following user's manual describes the details of the functions of the μ PD75402A(A). Be sure to read it before designing an application system.

μPD75402A User's Manual: IEU-644

FEATURES

- More reliable than the μ PD75402A
- High-speed operation with a minimum instruction execution time of 0.95 μ s (when the microcomputer operates at 4.19 MHz)
- Low voltage and low-speed instruction execution time of 15.3 μ s (when the microcomputer operates at 4.19 MHz)
- · Memory mapping by on-chip peripheral hardware
- · NEC standard serial bus interface (SBI)
- 8-bit basic interval timer (watchdog timer applicable)
- · Interrupt function
 - Three vectored interrupts (one external and two internal interrupts)
 - · One external test input
- Clock output function (remote controller output applicable)
- · Capable of specifying the incorporation of 16 pull-up resistors by software

APPLICATIONS

Electronic units for automobiles, and suchlike

ORDERING INFORMATION

Part number	Package	Quality grade
μ PD75402AC(A)- $\times\!\!\times\!\!\times$	28-pin plastic DIP (600 mil)	Special
μ PD75402ACT(A)- $\times\!\!\times\!\!$	28-pin plastic shrink DIP (400 mil)	Special
μ PD75402AGB(A)- \times \times -3B4	44-pin plastic QFP (10 \times 10 mm)	Special

Remark xxx indicates the ROM code number.

Please refer to "Quality Grades on NEC Semiconductor Devices" (Document number IEI-1209) published by NEC Corporation to know the specification of quality grade on the devices and its recommended applications.

The information in this document is subject to change without notice.



DIFFERENCES BETWEEN THE μ PD75402A(A) AND μ PD75402A

Product	μPD75402A(A)	μPD75402A
Quality grade	Special	Standard

FUNCTIONAL OVERVIEW

Item		Function	
Number of basic instructions		37	
Minimum instru execution time	ction	 0.95, 1.91, or 15.3 μs (when operating at 4.19 MHz) Switchable among three speeds 	
Built-in	ROM	1920 × 8 bits	
memory	RAM	64 × 4 bits	
General register	i	4 bits \times 4 or 8 bits \times 2 (memory mapping)	
I/O line		CMOS input ports: 6 lines CMOS I/O ports: 12 lines (8 lines can drive the LED directly.) N-ch open-drain I/O ports: 4 lines (All lines can drive the LED directly.)	
Pull-up resistor		 Capable of controlling the incorporation of 16 pull-up resistors by software Capable of controlling the incorporation of 4 pull-up resistors by mask option 	
Clock output		 1.05 MHz, 524 kHz, or 65.5 kHz (when operating at 4.19 MHz) Applicable to remote controller output 	
Timer/counter 8-bit basic interval timer (wat		8-bit basic interval timer (watchdog timer applicable)	
Serial interface		8 bits Two transfer modes (three-wire synchronous mode and SBI mode)	
Vectored interrupt		One external and two internal interrupts	
Test input		One external input (See Chapter 6 for details.)	
Standby		STOP/HALT mode	
Instruction set		 Bit manipulation instructions (set, clear, test, and Boolean operation) 1-byte relative branch instructions 4-bit operation instructions (add, Boolean operation, and compare) 4- and 8-bit transfer instructions 	
Package		 28-pin plastic DIP (600 mil) 28-pin plastic shrink DIP (400 mil) 44-pin plastic QFP (10 × 10 mm) 	



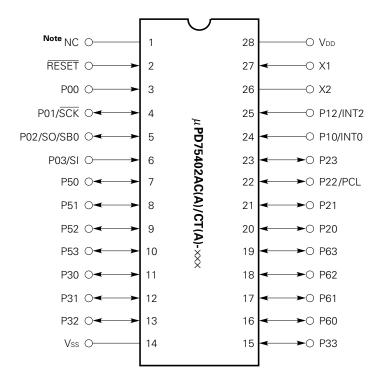
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1. PIN CONFIGURATION (TOP VIEW)

28-pin plastic DIP (600 mil), 28-pin plastic shrink DIP (400 mil)



P00 - P03 : Port 0 \overline{SCK} : Serial clock I/O

P10 and P12: Port 1 SO/SB0 : Serial output/input-output

P50 - P53 : Port 5 INT0 : External vectored interrupt input

P60 - P63 : Port 6 INT2 : External test input

X1 and X2: Oscillating pins

RESET : Reset input

RESET : Reset input

VDD : Power supply

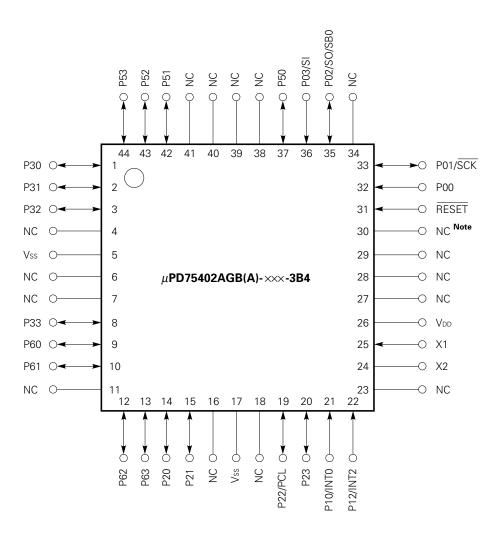
Vss : Ground

NC : No connection

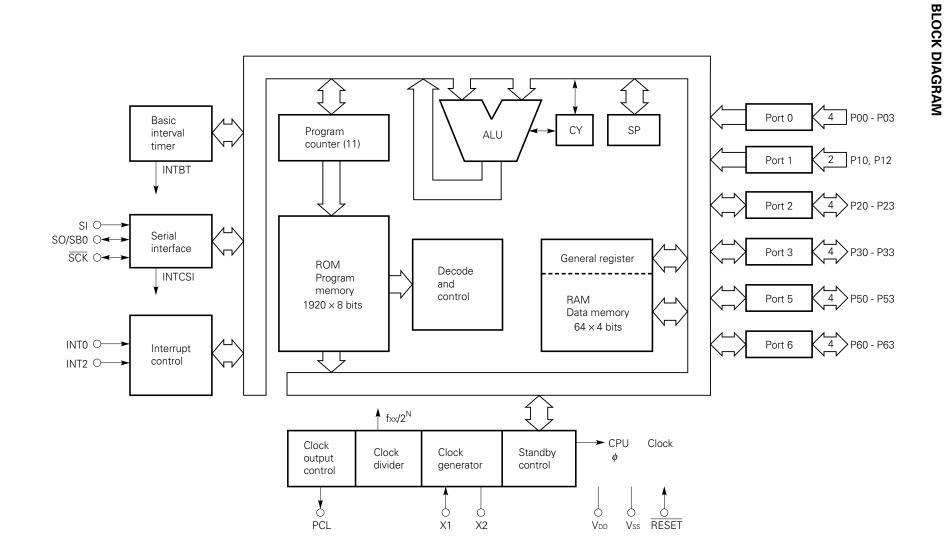
Note When the μ PD75402A(A) shares the printed circuit board with the μ PD75P402, connect the NC pin directly to the Vss pin.



44-pin plastic QFP (10 \times 10 mm)



Note When the μ PD75402A(A) shares the printed circuit board with the μ PD75P402, connect the NC pin (pin 30) directly to the Vss pin.





3. PIN FUNCTIONS

3.1 PORT PINS

Pin	I/O	Dual- function pin	Function	
P00	Input	-	4-bit input port (port 0)	
P01	I/O	SCK	P01 to P03 allow the connection of built-in pull-up resistors to be	
P02	I/O	SO/SB0	specified in units of three bits by software.	
P03	Input	SI		
P10	Input	INT0	2-bit input port (port 1) P10 connects with the built-in noise eliminator using a sampling clock.	
P12		INT2	 P12 connects with the built-in noise eliminator using an analog delay P12 allows the connection of built-in pull-up resistor to be specified to software. 	
P20	I/O	_	4-bit I/O port (port 2)	
P21		_	Allow I/O specification in units of four bits.	
P22		PCL	Allow the connection of built-in pull-up resistors to be specified in units of four bits by software.	
P23		_	, , , , , , , , , , , , , , , , , , , ,	
P30 - P33	I/O	-	Programmable 4-bit I/O port (port 3) Allow I/O specification bit by bit. Allow the connection of built-in pull-up resistors to be specified in units of four bits by software. Can directly drive LED.	
P50 - P53	I/O	-	4-bit N-ch open-drain I/O port (port 5) Allow I/O specification in units of four bits. Allow the connection of built-in pull-up resistors to be specified bit by bit by mask option. Can directly drive LED.	
P60 - P63	I/O	-	4-bit I/O port (port 6) Allow I/O specification in units of four bits. Allow the connection of built-in pull-up resistors to be specified in units of four bits by software. Can directly drive LED.	

Remarks 1. The μ PD75402A(A) cannot perform 8-bit I/O with two ports as a pair.

2. See Chapter 8 for each pin status during resetting.



3.2 NON-PORT PINS

Pin	I/O	Dual- function pin	Function	
INT0	Input	P10	Edge detection vectored interrupt request input pin (A detected edge can be selected by the mode register.) Connects with the built-in noise eliminator using a sampling clock.	
INT2	Input	P12	Edge detection external test input pin (A rising edge is detected.)	
SI	Input	P03	Serial data input pin	
so	I/O	P02/SB0	Serial data output pin	
SCK	I/O	P01	Serial clock I/O pin	
SB0	I/O	P02/SO	Serial bus I/O pin	
PCL	I/O	P22	Clock output pin	
X1, X2	Input	-	Pin for connection to a crystal/ceramic resonator for system clock generation. An external clock is applied to X1, and its reverse phase to X2.	
RESET	Input	-	System reset input pin, which connects with the built-in noise eliminator using an analog delay.	
VDD	_	-	Positive power supply pin	
Vss	_	_	Ground potential pin	
NC Note	_	-	No connection	

Remark See Chapter 8 for each pin status during resetting.

Note Connect the NC pin directly to the Vss pin when the μ PD75402A(A) shares the printed circuit board with the μ PD75P402 in emulation.

3.3 PIN INPUT/OUTPUT CIRCUITS

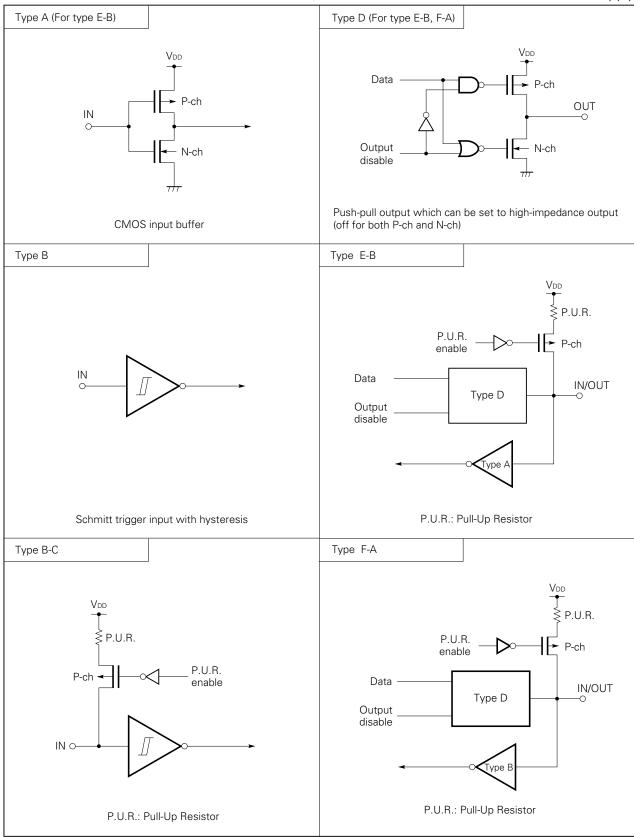
The I/O circuits of the μ PD75402A(A) are roughly shown on the next and subsequent pages.

Table 1-1 I/O Circuit Type of Pin

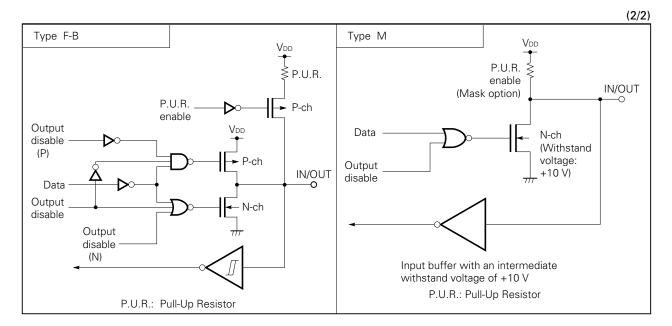
Pin	I/O type	Pin	I/O type
P00	B	P20, P21, and P23	E-B
P01/SCK	F-A	P22/PCL	
P02/SO/SB0	F-B	P30 - P33	E-B
P03/SI	B-C	P50 - P53	M
P10/INT0	B	P60 - P63	E-B
P12/INT2	B-C	RESET	B

Remark The types in circles have a Schmitt-triggered input.

(1/2)







3.4 SELECTION OF A MASK OPTION

The following mask options are provided for pins:



3.5 HANDLING UNUSED PINS

Pin	Recommended connection method	
P00	Connected to the Vss pin	
P01 - P03	When a pull-up resistor is contained Connected to the VDD pin	
P10, P12	When a pull-up resistor is not contained Connected to the Vss or Vpp pin	
P20 - P23	When a pull-up resistor is contained	
P30 - P33	Input mode : Connected to the VDD pin Output mode: Open	
P50 - P53	When a pull-up resistor is not contained	
P60 - P63	Input mode : Connected to the Vss or Vdd pin Output mode: Open	
NC	Open or directly connected to the Vss pin Note	

Note When the μ PD75402A(A) shares the printed circuit board with the μ PD75P402, connect the NC pin directly to Vss pin.

3.6 NOTES ON USING THE POO AND RESET PINS

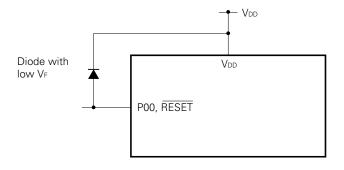
The P00 and $\overline{\text{RESET}}$ pins have the test mode selecting function for testing the internal operation of the μ PD75402A(A) (IC test), besides the functions shown in **Sections 3.1 and 3.2**.

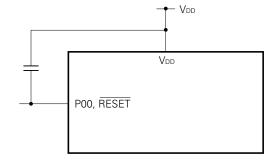
Applying a voltage exceeding V_{DD} to the P00 and/or $\overline{\text{RESET}}$ pin causes the μ PD75402A(A) to enter the test mode. When noise exceeding V_{DD} comes in during normal operation, the device is switched to the test mode.

For example, when the wiring from the P00 or RESET pin is too long, noise voltage induced on the wiring is applied to the pin, driving the voltage at the pin above VDD, which may cause malfunction.

When installing the wiring, lay the wiring in such a way that noise is suppressed as much as possible. If noise yet arises, use an external part to suppress it as shown below.

 Connect a diode with low V_F (0.3 V or lower) between the pin and V_{DD}. • Connect a capacitor between the pin and VDD.







4. MEMORY CONFIGURATION

• Program memory (ROM): 1920 × 8 bits (000H to 77FH)

· 000H and 001H: Vector table which contains the program start address after reset

• 002H to 009H : Vector table which contains the program start addresses when interrupts occur

Data memory

• Data area : 64×4 bits (000H to 03FH) • Peripheral hardware area: 128×4 bits (F80H to FFFH)

Fig. 4-1 Program Memory Map

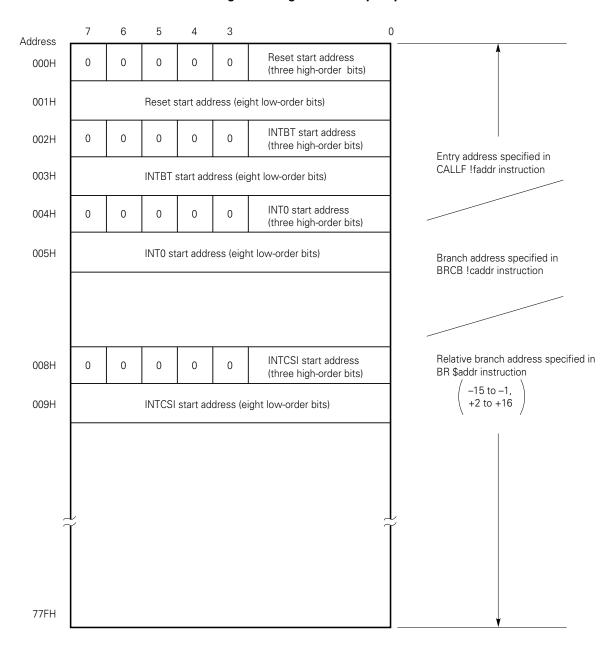




Fig. 4-2 Data Memory Map 000H General register (4×4) area 003H 004H Data area Static RAM (64 × 4) Bank 0 (64 × 4) 020H Stack area (32×4) 03FH No memory F80H Peripheral hardware Bank 15 128×4 area FFFH

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5. PERIPHERAL HARDWARE FUNCTIONS

5.1 PORTS

The μ PD75402A(A) has the following three types of I/O port:

• 6 CMOS input pins (PORT0 and PORT1)

• 12 CMOS I/O pins (PORT2, PORT3, and PORT6)

4 N-ch open-drain I/O pins (PORT5)

Total: 22 pins

Table 5-1 Functions of Ports

Port name	Function	Operation and feature	Remarks
PORT0 PORT1	4-bit Input	Allows read and test at any time regardless of the operation modes of dual function pins.	Also used for SO/SB0, SI, SCK, INT0, and INT2.
PORT3 Note	4-bit I/O	Allows input or output mode setting bit by bit.	_
PORT2 PORT6 Note		Allows input or output mode setting in units of 4 bits.	Port 2 is also used for PCL.
PORT5 Note	4-bit I/O (N-ch open-drain I/O with a withstand voltage of 10 V)	Allows input or output mode setting in units of 4 bits.	This port can incorporate a pull-up resistor as a mask option bit by bit.

Note PORT3, PORT5, and PORT6 can directly drive the LED.

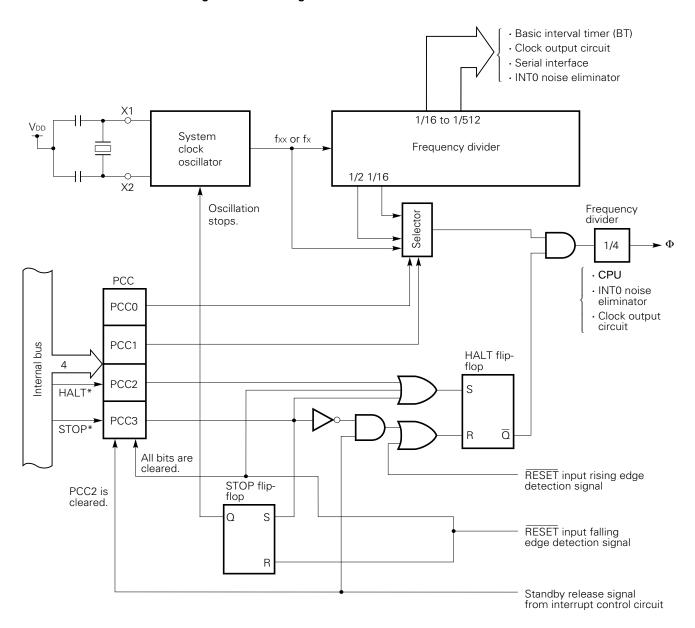


5.2 CLOCK GENERATOR

Operation of the clock generator is specified by the processor clock control register (PCC). The instruction execution time is variable.

• 0.95 μ s, 1.91 μ s, 15.3 μ s (when fxx is 4.19 MHz.)

Fig. 5-1 Block Diagram of the Clock Generator



Remarks 1. fxx = Crystal/ceramic oscillated frequency

- 2. fx = External clock frequency
- 3. $\Phi = CPU clock$
- 4. An asterisk (*) indicates instruction execution.
- 5. PCC: Processor clock control register
- **6.** One clock cycle (tcy) of Φ is equal to one machine cycle of an instruction. See AC characteristics of **Chapter 10** for details of tcy.



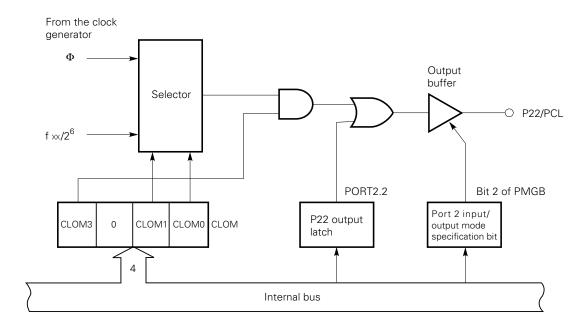
5.3 CLOCK OUTPUT CIRCUIT

The clock output circuit, which outputs clock pulses from pin P22/PCL, is used for supplying clock pulses for peripheral LSIs or for remote control output.

• Clock output (PCL): 1.05 MHz, 524 kHz, 65.5 kHz (when fxx is 4.19 MHz).

Fig. 5-2 shows the configuration of the clock output circuit.

Fig. 5-2 Configuration of the Clock Output Circuit



Remark The clock output circuit is designed not to output high-frequency pulses when clock output is switched between the enable and disable states.

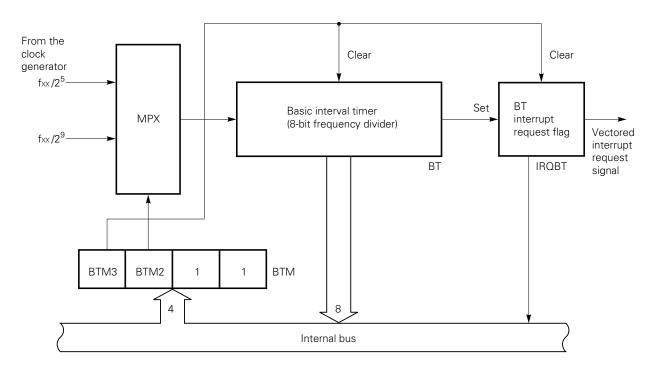


5.4 BASIC INTERVAL TIMER

The basic interval timer provides the following functions:

- · Interval timer operation that generates a reference time interrupt
- Can be used as a watchdog timer for detecting program crashes
- · Reading the count value

Fig. 5-3 Configuration of the Basic Interval Timer





5.5 SERIAL INTERFACE

The serial interface has the following modes:

- Three-wire serial I/O mode (MSB is transferred first.)
- SBI mode (MSB is transferred first.)

The three-wire serial I/O mode enables connections to be made with the 75X series, 78K series, and many other types of peripheral I/O devices.

The SBI mode enables communication with two or more devices.

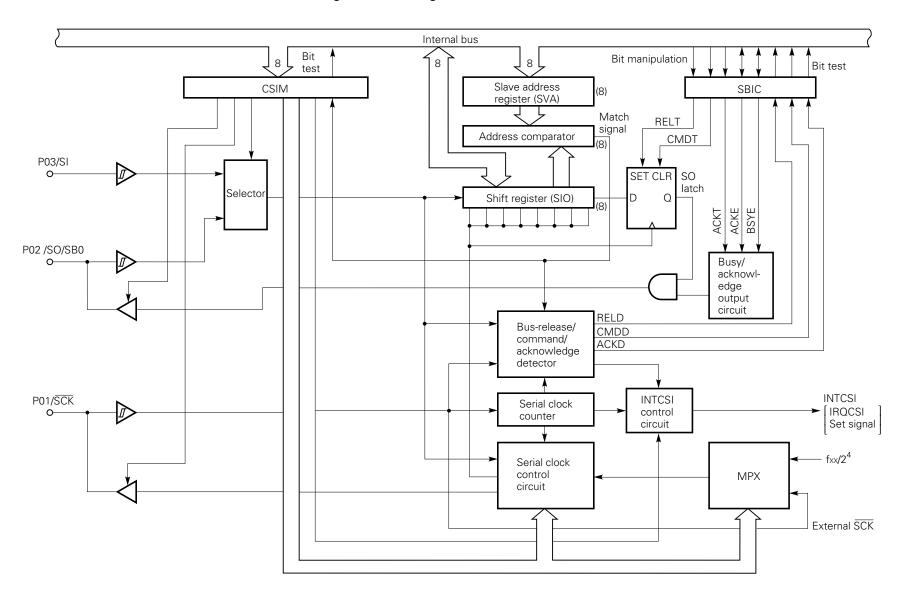


Fig. 5-4 Block Diagram of the Serial Interface



6. INTERRUPT FUNCTION

The μ PD75402A(A) has three interrupt sources and each of them has the interrupt vector table.

The μ PD75402A(A) is also provided with one edge-sensitive testable input signal.

When a vectored interrupt request is issued, the PC and PSW are saved in the stack, and the contents of the vector table which corresponds to the issued vectored interrupt are set in the PC as a start address. The program branches to the interrupt service routine. These operations are performed automatically by the hardware.

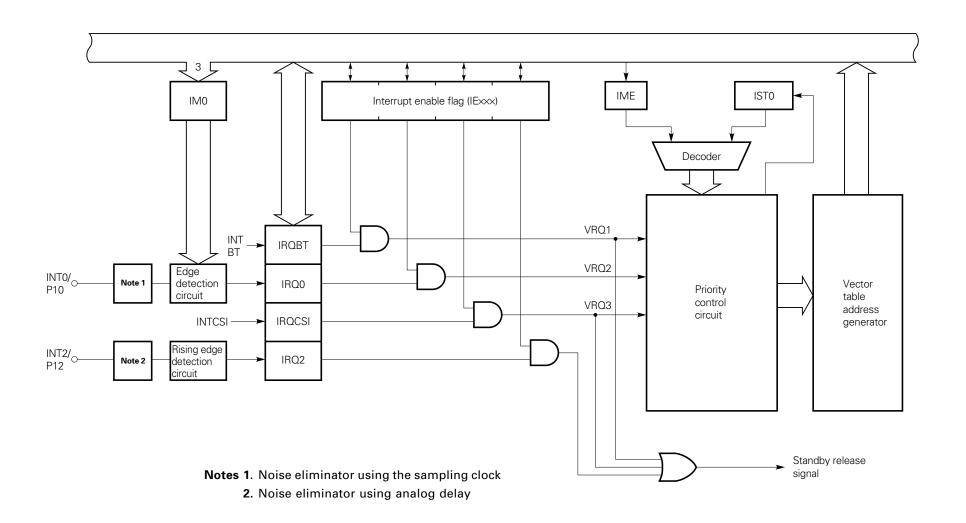
The flag is set by detecting the edge of the testable input signal, but a vectored interrupt request is not issued.

During execution of the interrupt service routine, the μ PD75402A(A) does not accept the other interrupt requests. Unlike the other 75X series, the μ PD75402A(A) cannot handle multiple interrupts.

The interrupt control circuit of the μ PD75402A(A) has the following functions.

- Vectored interrupt function under hardware control which can determine whether to accept an interrupt by an interrupt enable flag (IExxx) and an interrupt master enable flag (IME).
- · Any interrupt start address can be set.
- Test function of an interrupt request flag (IRQxxx) (Software can confirm that an interrupt occurs.)
- Release of the standby (HALT) mode (An interrupt to be released by an interrupt enable flag can be selected from interrupts other than INT0.)

Fig. 6-1 Block Diagram of Interrupt Control Circuit





7. STANDBY FUNCTION

To reduce the power consumption when the program is in the wait state, the μ PD75402A(A) has two standby modes, STOP and HALT.

Table 7-1 Operation Statuses in the Standby Mode

		STOP mode	HALT mode
Instruction set mode	on to be used to	STOP instruction	HALT instruction
Opera- tion Clock generator		Oscillation of the system clock stops.	Only the CPU clock (Φ) stops, but oscillation continues.
status	Basic interval timer	Operation stops.	Operates. (IRQBT is set at every reference time interval.)
	Serial interface	Operable only when the external SCK input is selected for the serial clock.	Operable
	Clock output circuit	Operation stops.	Clocks other than CPU clock (Φ) can be output.
	External interrupt	INT2 pin is usable. INT0 pin cannot be used.	INT2 pin is usable. INT0 pin cannot be used.
CPU		Operation stops.	
Release	signal	RESET input	RESET input or interrupt request signals enabled by the interrupt enable flags



8. RESET FUNCTION

When a low level signal is input to the RESET input pin, the state changes to the system reset. Table 8-1 shows the statuses of the hardware.

When the RESET signal rises from the low level to the high level, the reset state is released. The three low-order bits of the reset vector table whose address is 000H is set in bits 10 to 8 of the program counter (PC) and the contents of the reset vector table whose address is 001H is set in bits 7 to 0 of the PC. The program branches to that address and starts execution, i.e., the reset start address is programmable.

Initialize contents of registers in a program if necessary.

The RESET pin connects to the Schmitt-trigger circuit whose threshold level has hysteresis in the chip. This pin is also connected to the noise eliminator using an analog delay to eliminate narrow noise and prevent errors caused by noise. (See Fig. 8-1.)

For the power-on reset operation, be sure to allow sufficient time for oscillation to settle between power on and acceptance of the reset signal (see Fig. 8-2).

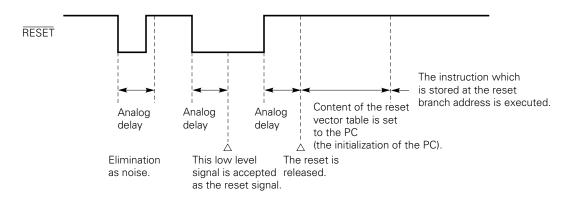


Fig. 8-1 Acceptance of the Reset Signal



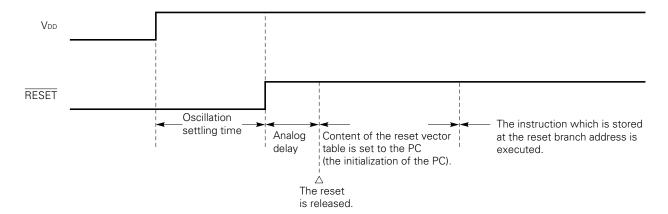




Table 8-1 Hardware Statuses after Reset Operations

		RESET input in standby mode	RESET input during operations
		Set the three low-order bits of address 000H in program memory in PC bits 10 to 8 and set the contents of address 001H in PC bits 7 to 0.	Set the three low-order bits of address 000H in program memory in PC bits 10 to 8 and set the contents of address 001H in PC bits 7 to 0.
PSW	Carry flag (CY)	Retained	Undefined
	Skip flag (SK0 - SK2)	0	0
	Interrupt status flag (IST0)	0	0
Stack poir	iter (SP)	Undefined	Undefined
Data mem	ory (RAM)	Retained Note	Undefined
General re	gister (X, A, H, L)	Retained	Undefined
Basic inter	val Counter (BT)	Undefined	Undefined
timer	Mode register (BTM)	0	0
Serial	Shift register (SIO)	Retained	Undefined
interface	Operation mode register (CSIM)	0	0
	SBI control register (SBIC)	0	0
	Slave address register (SVA)	Retained	Undefined
Clock gene tor and clo		0	0
output circ	Clock output mode register (CLOM)	0	0
Interrupt	Interrupt request flag (IRO×××)	Reset (0)	Reset (0)
	Interrupt enable flag (IExxx)	0	0
	Interrupt master enable flag (IME)	0	0
	INT0 mode register (IM0)	0	0
Digital I/O	Output buffer	Off	Off
port	Output latch	Cleared (0)	Cleared (0)
	I/O mode register (PMGA, PMGB)	0	0
	Pull-up resistor specification register (POGA)	0	0
States of p	Pins P00 - P03, P10, P12, P20 - P23, P30 - P33, P60 - P63	Used as inputs	Used as inputs
	P50 - P53	 High level when pull-up resistor is built in High impedance when open drain is used in the internal circuit 	 High level when pull-up resistor is built in High impedance when open drain is used in the internal circuit

Note Data in the data memory whose addresses are 38H to 3DH is not defined when the standby mode is released by the RESET input signal.



9. INSTRUCTION SET

(1) Representation format and description method of operands

An operand is described in the operand field of each instruction according to the description method corresponding to the operand representation format of the instruction refer to "RA75X Assembler Package User's Manual, Language" (EEU-1363) for details. When two or more elements are described in the description method field, select one of them. Upper-case letters, a number sign (#), and at mark (@), an exclamation mark (!), and a dollar sign (\$) are keywords, so they can be used without alteration. Specify an appropriate numeric value or label for immediate data.

The symbols of registers and flags can be used as labels instead of mem, fmem, and bit (refer to the "µPD75402A User's Manual" (IEU-644) for details). Some labels, however, cannot be specified in fmem.

Representation format	Description method
reg	X, A, H, L
reg1	X, H, L
rp	XA, HL
n4	4-bit immediate data or label
n8	8-bit immediate data or label
mem	8-bit immediate data or label Note
bit	2-bit immediate data or label
fmem	FB0H - FBFH/FF0H - FFFH immediate data or label
addr	11-bit immediate data or label
caddr	11-bit immediate data or label
faddr	11-bit immediate data or label
PORTn	PORT0 - PORT3, PORT5, PORT6
IExxx	IEBT, IECSI, IE0, IE2

Note Only an even address can be written in mem when 8-bit data is processed.

(2) Legend

A : A register, 4-bit accumulator

H : H registerL : L registerX : X register

XA : Register pair (XA), 8-bit accumulator

HL : Register pair (HL)PC : Program counterSP : Stack pointer

CY : Carry flag, bit accumulator
PSW : Program status word
PORTn: Port n (n = 0 to 3, 5, 6)
IME : Interrupt master enable flag

IExxx : Interrupt enable flag

PCC : Processor clock control register

· : Address/bit delimiter ($\times\times$) : Contents addressed by $\times\times$

××H : Hexadecimal data



(3) Explanation of the symbols in the addressing area field

*1	MB = 0	1
*2	MB = 0 (00H - 3FH) MB = 15 (80H - FFH)	Data memory addressing
*3	MB = 15, fmem = FB0H - FBFH or FF0H - FFFH	addressing
*4	addr = 000H - 77FH	<u> </u>
*5	addr = (Current PC) – 15 to (Current PC) – 1 or (Current PC) + 16 to (Current PC) + 2	Program memory
*6	caddr = 000H - 77FH	addressing
*7	faddr = 000H - 77FH	↓

Remarks 1. MB indicates an accessible memory bank.

2. *4 to *7 indicate each addressable area.

(4) Explanation of the machine cycle field

S indicates the number of machine cycles required for a skip instruction to perform skipping. The following shows the values of S.

- · When the next instruction is not skipped, S is 0.
- When the next instruction is skipped, S is 1.

A machine cycle is equal to one cycle (= tcv) of CPU clock Φ . A PCC setting determines the machine cycle. It can be set to one of three different periods.



Instruc- tion group	Mne- monic	Operand	Number of bytes	Ma- chine cycle	Operation	Address- ing area	Skip condition
Transfer	MOV	A, #n4	1	1	A ← n4		String A
instruc-		XA, #n8	2	2	XA ← n8		String A
tion		HL, #n8	2	2	HL ← n8		String B
		A, @HL	1	1	A ← (HL)	*1	
		@HL, A	1	1	(HL) ← A	*1	
		A, mem	2	2	A ← (mem)	*2	
		XA, mem	2	2	XA ← (mem)	*2	
		mem, A	2	2	(mem) ← A	*2	
		mem, XA	2	2	(mem) ← XA	*2	
	хсн	A, @HL	1	1	$A \leftrightarrow (HL)$	*1	
		A, mem	2	2	$A \leftrightarrow (mem)$	*2	
		XA, mem	2	2	XA ↔ (mem)	*2	
		A, reg1	1	1	A ↔ reg1		
	MOVT	XA, @PCXA	1	3	XA ← (PC ₁₀₋₈ + XA) _{ROM}		
Arithme-	ADDS	A, #n4	1	1 + S	A ← A + n4		carry
tic/ logical instruc-		A, @HL	1	1 + S	A ← A + (HL)	*1	carry
	ADDC	A, @HL	1	1	$A, CY \leftarrow A + (HL) + CY$	*1	
tion	AND	A, @HL	1	1	$A \leftarrow A \wedge (HL)$	*1	
	OR	A, @HL	1	1	$A \leftarrow A \lor (HL)$	*1	
	XOR	A, @HL	1	1	$A \leftarrow A \forall (HL)$	*1	
Accumu- lator manipu-	RORC	A	1	1	$CY \leftarrow \ A_0, \ A_3 \leftarrow CY, \ A_{n-1} \leftarrow A_n$		
lation instruc- tion	NOT	А	2	2	$A \leftarrow \overline{A}$		
Incre- ment/	INCS	reg	1	1 + S	reg ← reg + 1		reg = 0
decre- ment		mem	2	2 + S	(mem) ← (mem) + 1	*2	(mem) = 0
instruc- tion	DECS	reg	1	1 + S	reg ← reg – 1		reg = FH
Compari- son	SKE	reg, #n4	2	2 + S	Skip if reg = n4		reg = n4
instruc- tion		A, @HL	1	1 + S	Skip if A = (HL)	*1	A = (HL)
Carry flag	SET1	CY	1	1	CY ← 1		
manipu-	CLR1	CY	1	1	CY ← 0		
lation instruc-	SKT	CY	1	1 + S	Skip if CY = 1		CY = 1
tion	NOT1	CY	1	1	$CY \leftarrow \overline{CY}$		



Instruc- tion group	Mne- monic	Operand	Number of bytes	Ma- chine cycle	Operation	Address- ing area	Skip condition
Memory	SET1	mem.bit	2	2	(mem.bit) ← 1	*2	
bit		fmem.bit	2	2	(fmem.bit) ← 1	*3	
manipu- lation	CLR1	mem.bit	2	2	(mem.bit) ← 0	*2	
instruc-		fmem.bit	2	2	(fmem.bit) ← 0	*3	
tion	SKT	mem.bit	2	2 + S	Skip if (mem.bit) = 1	*2	(mem.bit) = 1
		fmem.bit	2	2 + S	Skip if (fmem.bit) = 1	*3	(fmem.bit) = 1
	SKF	mem.bit	2	2 + S	Skip if (mem.bit) = 0	*2	(mem.bit) = 0
		fmem.bit	2	2 + S	Skip if (fmem.bit) = 0	*3	(fmem.bit) = 0
	SKTCLR	fmem.bit	2	2 + S	Skip if (fmem.bit) = 1 and clear	*3	(fmem.bit) = 1
	AND1	CY, fmem.bit	2	2	$CY \leftarrow CY \land (fmem.bit)$	*3	
	OR1	CY, fmem.bit	2	2	$CY \leftarrow CY \lor (fmem.bit)$	*3	
	XOR1	CY, fmem.bit	2	2	CY ← CY ♥ (fmem.bit)	*3	
Branch instruc- tion	BR	addr	-	-	PC ₁₀₋₀ ← addr (The assembler selects an appropriate instruction from the BRCB !caddr and BR \$addr instructions.)	*4	
		\$addr	1	2	PC₁₀₋₀ ← addr	*5	
	BRCB	!caddr	2	2	PC₁₀₋₀ ← caddr	*6	
Subrou- tine stack	CALLF	!faddr	2	2	$(SP - 4)(SP - 1)(SP - 2) \leftarrow 0, PC_{10-0}$ $(SP - 3) \leftarrow 0000$ $PC_{10-0} \leftarrow faddr, SP \leftarrow SP - 4$	*7	
control instruc- tion	RET		1	3	\times , PC ₁₀₋₀ \leftarrow (SP)(SP + 3)(SP + 2) SP \leftarrow SP + 4		
tion	RETS		1	3 + S	\times , PC ₁₀₋₀ \leftarrow (SP)(SP + 3)(SP + 2) SP \leftarrow SP + 4, then skip unconditionally		Uncondition- ally
	RETI		1	3	\times , PC ₁₀₋₀ \leftarrow (SP)(SP + 3)(SP + 2) PSW \leftarrow (SP + 4)(SP + 5), SP \leftarrow SP + 6		
	PUSH	rp	1	1	$(SP - 1)(SP - 2) \leftarrow rp, SP \leftarrow SP - 2$		
	POP	rp	1	1	$rp \leftarrow (SP + 1)(SP), SP \leftarrow SP + 2$		
Interrupt	EI		2	2	IME (IPS.3) ← 1		
control instruc-		IExxx	2	2	IExxx ← 1		
tion	DI		2	2	IME (IPS.3) ← 0		
		IExxx	2	2	IE××× ← 0		
Input/ output	IN	A, PORTn	2	2	A ← PORTn (n = 0 - 3, 5, 6)		
instruc- tion	OUT	PORTn, A	2	2	PORT n ← A (n = 2, 3, 5, 6)		
CPU	HALT		2	2	Set HALT mode (PCC.2 ← 1)		
control instruction	STOP		2	2	Set STOP mode (PCC.3 ← 1)		
	NOP		1	1	No operation		



10. ELECTRICAL CHARACTERISTICS

ABSOLUTE MAXIMUM RATINGS $(T_a = 25 \degree C)$

Parameter	Symbol		Conditions		Rated value	Unit
Supply voltage	V _{DD}				-0.3 to +7.0	V
Input voltage	Vıı	Ports ot	her than port 5		-0.3 to V _{DD} + 0.3	V
	Vı2	Port 5	Built-in pull-up resis	-0.3 to V _{DD} + 0.3	V	
			Open drain		-0.3 to +11.0	V
Output voltage	Vo				-0.3 to V _{DD} + 0.3	V
High-level output	Іон	Each pir	1		-15	mA
current		Total of	all output pins	-30	mA	
Low-level output current	loL Note	One pin of port 0, 3, 5, or 6		Peak value	30	mA
				rms	15	mA
		One pin	of port 2	Peak value	20	mA
				rms	10	mA
		Total of	all pins of ports 0, 3,	Peak value	100	mA
		and 5 (e	xcl. P33)	rms	60	mA
		Total of	all pins of ports 2, 6,	Peak value	100	mA
		and P33		rms	60	mA
Operating temperature	Topt				-40 to +85	°C
Storage tempera- ture	T _{stg}				-65 to +150	°C

Note Calculate rms with [rms] = [peak value] $\times \sqrt{\text{duty.}}$

Caution Absolute maximum ratings are rated values beyond which some physical damages may be caused to the product; if any of the parameters in the table above exceeds its rated value even for a moment, the quality of the product may deteriorate. Be sure to use the product within the rated values.



CHARACTERISTICS OF THE OSCILLATION CIRCUIT (Ta = -40 to +85 °C, V DD = 2.7 to 6.0 V)

Resonator	Recommended constant	Parameter	Conditions	Min.	Тур.	Max.	Unit
Ceramic resonator	X1 X2	Oscillator frequency (fxx) Note 1	V _{DD} = oscillation voltage range	2.0		5.0 Note 3	MHz
	C1 C2	Oscillation settling time Note 2	After V _{DD} reaches MIN. of the oscilla- tion voltage range	2.0 4.19	4	ms	
Crystal	X1 X2	Oscillator frequency (fxx) Note 1		2.0	4.19	5.0 Note 3	MHz
	C1 C2	Oscillation settling time Note 2	V _{DD} = 4.5 to 6.0 V			10	ms
External clock	X1 X2	X1 input frequency (fx) Note 1		2.0		5.0 Note 3	MHz
	μPD74HCU04	X1 input high/low level width (txH, txL)		100		250	ns

- **Notes 1.** The oscillator frequency and X1 input frequency indicate only the oscillator characteristics. See the item of AC characteristics for the instruction execution time.
 - 2. The oscillation settling time means the time required for the oscillation to settle after VDD is applied or after the STOP mode is released.
 - 3. When 4.19 MHz < $fx \le 5.0$ MHz, do not select PCC = 0011 as the instruction execution time. When PCC = 0011, one machine cycle falls short of 0.95 μ s, the minimum value for the standard.
- ★ Caution When the clock oscillator is used, conform to the following guidelines when wiring at the portions surrounded by dotted lines in the figures above to eliminate the influence of the wiring capacity.
 - · The wiring must be as short as possible.
 - Other signal lines must not run in these areas.
 - Any line carrying a high fluctuating current must be kept away as far as possible.
 - The grounding point of the capacitor of the oscillator must have the same potential as that of Vss. It must not be grounded to ground patterns carrying a large current.
 - · No signal must be taken from the oscillator.

CAPACITANCE $(T_a = 25 \, ^{\circ}C, \, V_{DD} = 0 \, V)$

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	Cin	f = 1 MHz			15	pF
Output capacitance	Соит	0 V for pins other than pins to be			15	pF
I/O capacitance	Сю	measured			15	pF



DC CHARACTERISTICS ($T_a = -40 \text{ to } +85 ^{\circ}\text{C}$, $V_{DD} = 2.7 \text{ to } 6.0 \text{ V}$)

Parameter	Symbol		Condit	ions		Min.	Тур.	Max.	Unit
High-level input	V _{IH1}	Ports 2, 3, an	d 6			0.7V _{DD}		V _{DD}	V
voltage	V _{IH2}	Ports 0 and 1	, and RES	SET		0.8V _{DD}		V _{DD}	V
	V _{IH3}	Port 5	Built-in	pull-up	resistor	0.7V _{DD}		V _{DD}	V
			Open d	rain		0.7V _{DD}		10	V
	V _{IH4}	X1 and X2	X1 and X2			V _{DD} - 0.5		V _{DD}	V
Low-level input	V _{IL1}	Ports 2, 3, 5,	and 6			0		0.3V _{DD}	V
voltage	V _{IL2}	Ports 0 and 1	, and RES	SET		0		0.2V _{DD}	V
	V _{IL3}	X1 and X2				0		0.4	V
High-level output	Vон	Ports 0, 2,	$V_{DD} = 4.5 \text{ to } 6.0 \text{ V, loh} = -1 \text{ mA}$			V _{DD} - 1.0			V
voltage		3, and 6	Іон = −10	Іон = -100 μА		V _{DD} - 0.5			V
Low-level output voltage	VoL	Ports 3, 5, and 6	V _{DD} = 4.5	5 to 6.0	V, IoL = 15 mA		0.6	2.0	V
		Ports 0, 2,	V _{DD} = 4.5	to 6.0	V, loL = 1.6 mA			0.4	V
		3, 5, and 6	loL = 40	IoL = 400 μA				0.5	V
		SB0 (Open drain)	Pull-up resistor : 1 k Ω or more V _{DD} = 4.5 to 6.0 V				0.2V _{DD}	V	
High-level input	ILIH1	VIN = VDD	Other th	nan X1	and X2			3	μΑ
leakage current	ILIH2		X1 and	X1 and X2				20	μΑ
	Ілнз	Vin = 10 V	Port 5 (open drain)				20	μΑ	
Low-level input	ILIL1	Vin = 0 V	Other th	nan X1	and X2			- 3	μΑ
leakage current	ILIL2		X1 and	X2				- 20	μΑ
High-level output	Ігон1	Vout = Vdd	Other th	nan poi	rt 5			3	μΑ
leakage current	110н2	Vout = 10 V	Port 5 (open d	rain)			20	μΑ
Low-level output leakage current	Ісос	Vout = 0 V						- 3	μΑ
Built-in pull-up	R _{L1}	Ports 0, 1, 2,		V _{DD} =	5.0 V ±10 %	15	40	80	kΩ
resistor		6 (excl. P00 a P10) V _{IN} = 0 V		V _{DD} =	3.0 V ±10 %	30		300	kΩ
	R _{L2}	Port 5		V _{DD} =	5.0 V ±10 %	15	40	70	kΩ
		Vout = VDD - 2	.0 V	V _{DD} =	3.0 V ±10 %	10		60	kΩ
Power supply	I _{DD1}	4.19 MHz	V _{DD} = 5	.0 V ±1	0 % Note 2		2.5	8	mA
current Note 1		crystal	V _{DD} = 3	.0 V ±1	0 % Note 3		0.5	1.5	mA
	I _{DD2}	resonance C1 = C2 =	HALT	V _{DD} =	= 5.0 V ±10 %		500	1500	μΑ
		22 pF	mode	V _{DD} =	= 3.0 V ±10 %		150	450	μΑ
	IDD3	STOP	V _{DD} = 5.0 V ±10 %			0.5	20	μΑ	
		mode	V _{DD} =	V _{DD} =			0.1	10	μΑ
			3.0 V ±	10 %	T _a = 25 °C		0.1	5	μΑ

Notes 1. This current excludes the current which flows through the built-in pull-up resistors.

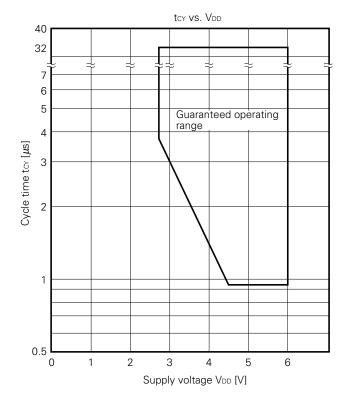
- 2. Value when the processor clock control resistor (PCC) is set to 0011 and the μ PD75402A(A) is operated in the high-speed mode
- 3. Value when the PCC is set to 0000 and the μ PD75402A(A) is operated in the low-speed mode



AC CHARACTERISTICS ($T_a = -40$ to +85 °C, V DD = 2.7 to 6.0 V, Vss = 0 V)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
CPU clock cycle time Note 1	tcy	V _{DD} = 4.5 to 6.0 V	0.95		32	μs
(minimum instruction execution time = one machine cycle)	·		3.8		32	μs
Interrupt input high/low level	tinth, tintl	INT0	Note 2			μs
width		INT2	10			μs
RESET low-level width	trsl		10			μs

- Notes 1. The cycle time of the CPU clock (Φ) (minimum instruction execution time) depends on the connected resonator frequency and the setting of the processor clock control register (PCC). The figure on the right side shows the cycle time tcy characteristics for the supply voltage VDD.
 - 2. This value is 2tcy or 128/fxx according to the setting of the interrupt mode register (IM0).





Serial transfer operation

Three-wire serial I/O mode (SCK ... Internal clock output):

Parameter	Symbol	Cond	ditions	Min.	Тур.	Max.	Unit
SCK cycle time	tkcy1	V _{DD} = 4.5 to 6.0 V	V _{DD} = 4.5 to 6.0 V				ns
				3800			ns
SCK high/low level	t _{KL1}	V _{DD} = 4.5 to 6.0 V		tксү1/2 – 50			ns
width	t кн1			tксү1/2 - 150			ns
SI setup time (referred to SCK1)	tsıĸ1			150			ns
SI hold time (referred to SCK1)	t KSI1			400			ns
Delay from SCK↓ to	tkso1	$R_L = 1 k\Omega$,	V _{DD} = 4.5 to 6.0 V	0		250	ns
SO output		C _L = 100 pF Note		0		1000	ns

Note R_L and C_L are the resistance and capacitance of the SO output line load respectively.

Three-wire serial I/O mode (SCK ··· External clock input):

Parameter	Symbol	Cone	ditions	Min.	Тур.	Max.	Unit
SCK cycle time	tkcy2	V _{DD} = 4.5 to 6.0 V	V _{DD} = 4.5 to 6.0 V				ns
				3200			ns
SCK high/low level	tĸL2	V _{DD} = 4.5 to 6.0 V	V _{DD} = 4.5 to 6.0 V				ns
width tkH2			1600			ns	
SI setup time (referred to SCK1)	tsıĸ2			100			ns
SI hold time (referred to SCK1)	tksi2			400			ns
Delay from SCK↓ to	tkso2	$R_L = 1 k\Omega$,	V _{DD} = 4.5 to 6.0 V	0		300	ns
SO output		C _L = 100 pF Note		0		1000	ns

 $\textbf{Note} \;\; \mathsf{RL} \; \mathsf{and} \; \mathsf{CL} \; \mathsf{are} \; \mathsf{the} \; \mathsf{resistance} \; \mathsf{and} \; \mathsf{capacitance} \; \mathsf{of} \; \mathsf{the} \; \mathsf{SO} \; \mathsf{output} \; \mathsf{line} \; \mathsf{load} \; \mathsf{respectively}.$



SBI mode (SCK ··· Internal clock output (master)):

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
SCK cycle time	tксүз	V _{DD} = 4.5 to 6.0 V	1600			ns
			3800			ns
SCK high/low level	tкьз	V _{DD} = 4.5 to 6.0 V	tксүз/2 – 50			ns
width	tкнз		tксүз/2 – 150			ns
SB0 setup time (referred to SCK1)	tsıкз		150			ns
SB0 hold time (referred to SCK↑)	tksi3		tксүз/2			ns
Delay from SCK↓ to	tкsоз	V _{DD} = 4.5 to 6.0 V	0		250	ns
SB0 output			0		1000	ns
Delay from SCK↑ to SB0↓	tкsв		tксүз			ns
Delay from SB0↓ to SCK	tsвк		t ксүз			ns
SB0 low-level width	t sbl		tксүз			ns
SB0 high-level width	tsвн		tксүз			ns

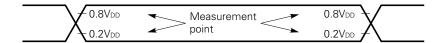
SBI mode (SCK ... External clock input (slave)):

Parameter	Symbol	Cond	Min.	Тур.	Max.	Unit	
SCK cycle time	tkcy4	V _{DD} = 4.5 to 6.0 V	800			ns	
				3200			ns
SCK high/low level width	tĸL4	V _{DD} = 4.5 to 6.0 V		400			ns
	tĸн4			1600			ns
SB0 setup time (referred to SCK↑)	tsıĸ4			100			ns
SB0 hold time (referred to SCK↑)	tksi4			tксү4/2			ns
Delay from SCK↓ to SB0 output	tkso4	$R_L = 1 \text{ k}\Omega,$ $C_L = 100 \text{ pF }^{\text{Note}}$	V _{DD} = 4.5 to 6.0 V	0		300	ns
				0		1000	ns
Delay from SCK↑ to SB0↓	tкsв			tKCY4			ns
Delay from SB0↓ to SCK↓	tsвк			tKCY4			ns
SB0 low-level width	tsbl			tKCY4			ns
SB0 high-level width	tsвн			tKCY4			ns

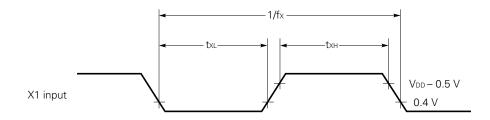
 $\textbf{Note} \quad \text{RL and } \textbf{CL} \text{ are the resistance and capacitance of the SO output line load respectively}.$



AC Timing Measurement Points (Excluding X1 Input)

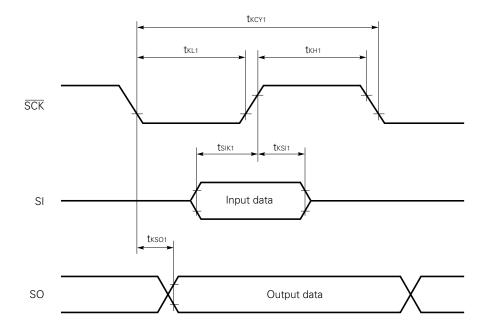


Clock Timing



Serial Transfer Timing

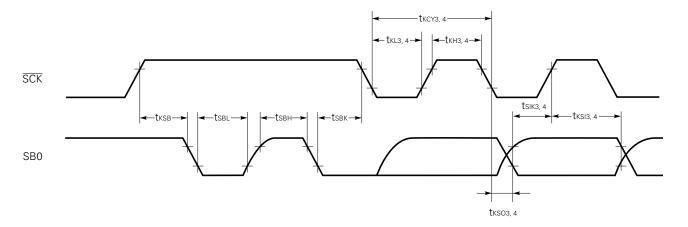
Three-wire serial I/O mode:



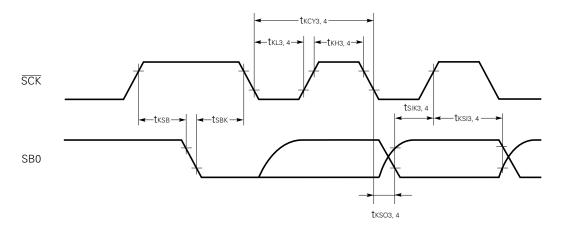


Serial Transfer Timing

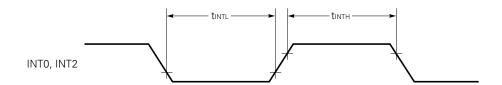
Bus release signal transfer:



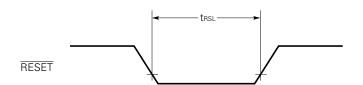
Command signal transfer:



Interrupt Input Timing



RESET Input Timing

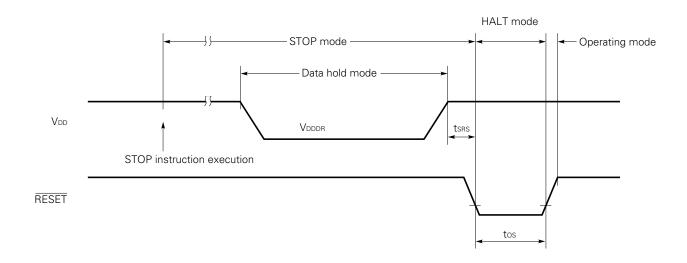




DATA HOLD CHARACTERISTICS AT LOW SUPPLY VOLTAGE IN DATA MEMORY STOP MODE (Ta = -40 to +85 $^{\circ}\text{C}$)

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Data hold supply voltage	VDDDR		2.0		6.0	>
Data hold supply current	Idddr	VDDDR = 2.0 V		0.1	10	μΑ
RESET setup time	tsrs		0			μs
Oscillation settling time	tos	After V _{DD} reaches the oscillation voltage range when the ceramic resonator is connected			4	ms
		After V _{DD} reaches the oscillation voltage range when the crystal is connected			10	ms

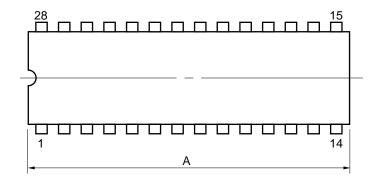
Data Hold Timing (STOP Mode Release by RESET)

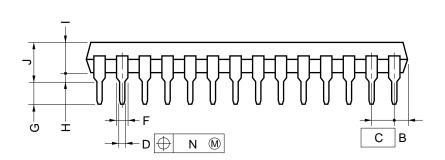


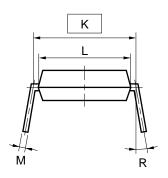


11. PACKAGE DIMENSIONS

28 PIN PLASTIC DIP (600 mil)







NOTES

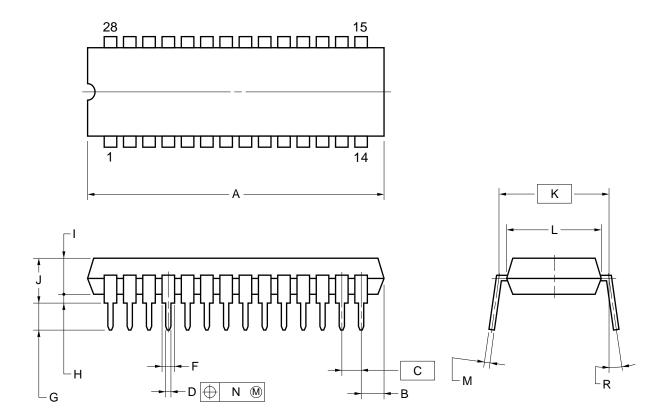
- 1) Each lead centerline is located within 0.25 mm (0.01 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

ITEM	MILLIMETERS	INCHES
Α	38.10 MAX.	1.500 MAX.
В	2.54 MAX.	0.100 MAX.
С	2.54 (T.P.)	0.100 (T.P.)
D	0.50±0.10	$0.020^{+0.004}_{-0.005}$
F	1.2 MIN.	0.047 MIN.
G	3.6±0.3	0.142±0.012
Н	0.51 MIN.	0.020 MIN.
- 1	4.31 MAX.	0.170 MAX.
J	5.72 MAX.	0.226 MAX.
K	15.24 (T.P.)	0.600 (T.P.)
L	13.2	0.520
М	$0.25^{+0.10}_{-0.05}$	$0.010^{+0.004}_{-0.003}$
N	0.25	0.01
R	0 \15°	0 \15°
		200 100 500 1 1

P28C-100-600A1-1



28PIN PLASTIC SHRINK DIP (400 mil)



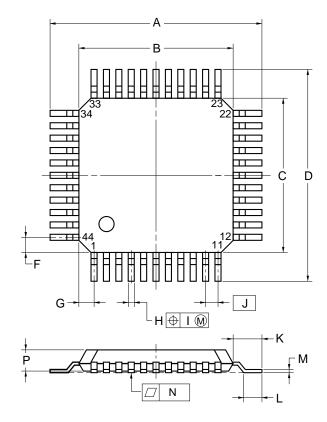
NOTES

- 1) Each lead centerline is located within 0.17 mm (0.007 inch) of its true position (T.P.) at maximum material condition.
- 2) Item "K" to center of leads when formed parallel.

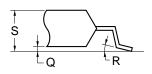
ITEM	MILLIMETERS	INCHES
Α	28.46 MAX.	1.121 MAX.
В	2.67 MAX.	0.106 MAX.
С	1.778 (T.P.)	0.070 (T.P.)
D	0.50±0.10	$0.020^{+0.004}_{-0.005}$
F	0.9 MIN.	0.035 MIN.
G	3.2±0.3	0.126±0.012
Н	0.51 MIN.	0.020 MIN.
1	4.31 MAX.	0.170 MAX.
J	5.08 MAX.	0.200 MAX.
K	10.16 (T.P.)	0.400 (T.P.)
L	8.6	0.339
М	0.25 ^{+0.10} -0.05	$0.010^{+0.004}_{-0.003}$
N	0.17	0.007
R	0~15°	0~15°
		D20C 70 400A 4

P28C-70-400A-1

44 PIN PLASTIC QFP (□10)



detail of lead end



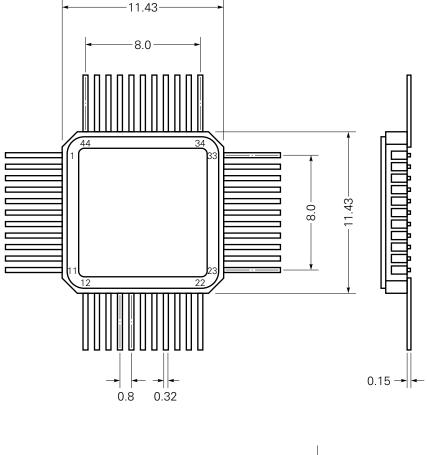
NOTE

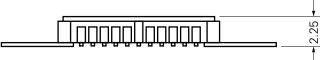
Each lead centerline is located within 0.15 mm (0.006 inch) of its true position (T.P.) at maximum material condition.

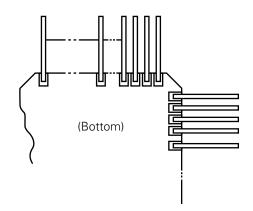
ITEM	MILLIMETERS	INCHES
Α	13.6±0.4	$0.535^{+0.017}_{-0.016}$
В	10.0±0.2	$0.394^{+0.008}_{-0.009}$
С	10.0±0.2	$0.394^{+0.008}_{-0.009}$
D	13.6±0.4	0.535 ^{+0.017} -0.016
F	1.0	0.039
G	1.0	0.039
Н	0.35±0.10	0.014+0.004
I	0.15	0.006
J	0.8 (T.P.)	0.031 (T.P)
K	1.8±0.2	$0.071^{+0.008}_{-0.009}$
L	0.8±0.2	0.031+0.009
М	$0.15^{+0.10}_{-0.05}$	$0.006^{+0.004}_{-0.003}$
N	0.10	0.004
Р	2.7	0.106
Q	0.1±0.1	0.004±0.004
R	5°±5°	5°±5°
S	3.0 MAX.	0.119 MAX.

P44GB-80-3B4-3

PACKAGE DIMENSIONS OF THE 44-PIN CERAMIC QFP FOR ES (REF. DWG.) (UNIT: MM)







Cautions 1. Find the location of pin 1 by checking the location of pin 17, which is connected to the metal cap.

- 2. The metal cap is connected to pin 17. The electrical level of the metal cap is Vss (GND).
- 3. The lead length has not been specified because leads are cut without any detailed specifications.



12. RECOMMENDED SOLDERING CONDITIONS

The following conditions shall be met when soldering the μ PD75402A(A).

For details of the recommended soldering conditions, refer to our document "SMD Surface Mount Technology Manual" (IEI-1207).

Please consult with our sales offices in case other soldering process is used, or in case soldering is done under different conditions.

Table 12-1 Soldering Conditions for Surface-Mount Devices

 μ PD75402AGB(A)- $\times\times$ -3B4: 44-pin plastic QFP (10 \times 10 mm)

Soldering process	Soldering conditions	Symbol
Infrared ray reflow	Peak package's surface temperature: 230 °C Reflow time: 30 seconds or less (210 °C or more) Number of reflow processes: 1	IR30-00-1
VPS	Peak package's surface temperature: 215 °C Reflow time: 40 seconds or less (200 °C or more) Number of reflow processes: 1	VP15-00-1
Wave soldering	Solder temperature: 260 °C or less Flow time: 10 seconds or less Number of flow processes: 1 Preheating temperature: 120 °C max. (measured on the package surface)	WS60-00-1
Partial heating method	Terminal temperature: 300 °C or less Flow time: 3 seconds or less (for each side of device)	_

Caution Do not apply more than a single process at once, except for "Partial heating method."

Table 12-2 Soldering Conditions for Insertion-Mount Devices

 μ PD75402AC(A)- $\times\times$: 28-pin plastic DIP (600 mil)

 μ PD75402ACT(A)- $\times\times$: 28-pin plastic shrink DIP (400 mil)

Soldering process	Soldering conditions
Wave soldering (Only for leads)	Solder temperature: 260 °C or less Flow time: 10 seconds or less
Partial heating method	Terminal temperature: 260 °C or less Flow time: 10 seconds or less

Caution In wave soldering, apply solder only to the lead section. Care must be taken that jet solder does not come in contact with the main body of the package.

- Notice -

Other versions of the products are available. For these versions, the recommended reflow soldering conditions have been mitigated as follows:

Higher peak temperature (235 $^{\circ}$ C), two-stage, and longer exposure limit.

Contact an NEC representative for details.



APPENDIX A DIFFERENCES BETWEEN THE μ PD75402A(A) AND μ PD75P402

Item	Product	μPD75402A(A) μPD75P402		μPD75P402		
ROM		Masked ROM		Masked ROM	One-time PROM	
I/O ports	Input	22	6	1 (Pull-up resistors can be	-	
	N-ch I/O		4 (Pu	-up resistors can be connected by 4 (No pull-up resistors can be conneption.)		
V _{PP} , PROM program- ming pin			•	Not provided	Provided	
Electrical Operating charac- supply teristics voltage				2.7 to 6.0 V	5 V ±10 %	
	Operating temperature			-40 to +85 °C	-10 to +70 °C	
Quality grade				Special	Standard	



APPENDIX B DEVELOPMENT TOOLS

The following development tools are provided for developing systems including the μ PD75402A(A)

	IE-75000 IE-75001		In-circuit emulator for the 75X series
	IE-75000-R-EM ^{Note 2}		Emulation board for the IE-75000-R and IE-75001-R
, o	EP-75402	2C-R	Emulation probe for the μ PD75402AC(A) and μ PD75402ACT(A)
Hardware	EP-75402GB-R EV-9200G-44		Emulation probe for the μ PD75402AGB(A). A 44-pin conversion socket, the EV-9200G-44, is attached to the probe.
_	PG-1500		PROM programmer
	PA-75P402CT		PROM programmer adapter for the μ PD75P402C and μ PD75P402CT. Connected to the PG-1500.
	PA-75P402GB		PROM programmer adapter for the μ PD75P402GB. Connected to the PG-1500.
	IE control program PG-1500 controller		Host machine
Software			 PC-9800 series (MS-DOSTM Ver. 3.30 to Ver. 5.00A^{Note 3}) IBM PC/ATTM (PC DOSTM Ver. 3.1)
Soft	RA75X reassemble	elocatable er	

Notes 1. Maintenance service only

- 2. Not contained in the IE-75001-R
- 3. These software cannot use the task swap function, which is available in MS-DOS Ver. 5.00 and Ver. 5.00A.

Remark Refer to "75X Series Selection Guide" (IF-1027) for development tools manufactured by third parties.

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APPENDIX C RELATED DOCUMENTS

Documents related to the device

Document name	Document No.
User's manual	IEU-644
Application note	IEA-638
75X series selection guide	IF-1027

Documents related to development tools

	Document No.			
	IE-75000-R/IE-75001-R User's Manual	EEU-1416		
<u>re</u>	EEU-1294			
rdwa	EP-75402C-R User's Manual EP-75402C-R User's Manual EP-75402GR-R User's Manual			
На	EEU-702			
	EEU-1335			
e e	RA75X Assembler Package User's Manual	EEU-1346		
Software		Language	EEU-1363	
So	PG-1500 Controller User's Manual	EEU-1291		

Other related documents

Document name	Document No.
Package Manual	IEI-1213
SMD Surface Mount Technology Manual	IEI-1207
Quality Grades on NEC Semiconductor Devices	IEI-1209
NEC Semiconductor Device Reliability/Quality Control System	IEI-1203
Electrostatic Discharge (ESD) Test	IEI-1201
Guide to Quality Assurance for Semiconductor Devices	MEI-1202

Caution The above documents may be revised without notice. Use the latest versions when you design an application system.



Cautions on CMOS Devices

① Countermeasures against static electricity for all MOSs

Caution When handling MOS devices, take care so that they are not electrostatically charged.

Strong static electricity may cause dielectric breakdown in gates. When transporting or storing MOS devices, use conductive trays, magazine cases, shock absorbers, or metal cases that NEC uses for packaging and shipping. Be sure to ground MOS devices during assembling. Do not allow MOS devices to stand on plastic plates or do not touch pins.

Also handle boards on which MOS devices are mounted in the same way.

② CMOS-specific handling of unused input pins

Caution Hold CMOS devices at a fixed input level.

Unlike bipolar or NMOS devices, if a CMOS device is operated with no input, an intermediate-level input may be caused by noise. This allows current to flow in the CMOS device, resulting in a malfunction. Use a pull-up or pull-down resistor to hold a fixed input level. Since unused pins may function as output pins at unexpected times, each unused pin should be separately connected to the VDD or GND pin through a resistor.

If handling of unused pins is documented, follow the instructions in the document.

(3) Statuses of all MOS devices at initialization

Caution The initial status of a MOS device is unpredictable when power is turned on.

Since characteristics of a MOS device are determined by the amount of ions implanted in molecules, the initial status cannot be determined in the manufacture process. NEC has no responsibility for the output statuses of pins, input and output settings, and the contents of registers at power on. However, NEC assures operation after reset and items for mode setting if they are defined.

When you turn on a device having a reset function, be sure to reset the device first.

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[MEMO]

NEC μ PD75402A(A)

[MEMO]

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Application examples recommended by NEC Corporation

Standard: Computer, Office equipment, Communication equipment, Test and Measurement equipment, Machine tools, Industrial robots, Audio and Visual equipment, Other consumer products, etc.

Special: Automotive and Transportation equipment, Traffic control systems, Antidisaster systems, Anticrime

systems, etc.

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